Electronic Supplementary Information for:

High Temperature Ferromagnetism in π -Conjugated Two-Dimensional Metal-Organic Frameworks

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Computational Methods

Density functional theory (DFT) calculations were carried out using the Vienna ab initio Simulation Package (VASP)^{1,2}, version 5.3.3. The electronic wavefunctions were expanded in a plane-wave basis set with a kinetic energy cutoff of 500 eV. Electron-ion interactions were described using the projector augmented wave (PAW) method^{3,4}. Generalized gradient approximation (GGA)⁵ of the exchange-correlation energy in the form of Perdew-Burke-Ernzerhoff (PBE)⁶ was applied. We used the Dudarev implementation of DFT+U method^{7,8} to describe the localized *d* orbitals of transition metal atoms. The effective Coulomb (*U*) and exchange (*J*) parameters being used are described in the main text. All calculations were carried out in spin-polarized conditions⁹. The initial magnetic moments of the transition metal atoms were set to be their corresponding electronic magnetic moments in the non-bonding atomic limit, using the MAGMOM tag in VASP. We find that the relaxed magnetic moments and energies for most of the systems studied in this work does not depend on the initial magnetic moments being supplied. One exception is the NiFePc MOF system, for which convergence was found to be exceptionally difficult. In this case, we started the spin-polarized calculations with the charge density obtained from converged non-spin-polarized calculations.

The MOF monolayers were modelled by adding sufficiently large vacuum space along the out-of-plane direction in the structural model (20 Å for 1×1 structural unit cell and 15 Å for $\sqrt{2} \times \sqrt{2}$ supercell). We adopted the Monkhorst-Pack¹⁰ scheme of **k**-point sampling for Brillouin zone integration, with $6 \times 6 \times 1$ and $4 \times 4 \times 1$ Γ -centered grid for unit cell and $\sqrt{2} \times \sqrt{2}$ supercell respectively. These **k**-points were sufficient to achieve a convergence in total energy less than 0.05 meV per atom. For bulk systems, a $6 \times 6 \times 5$ **k**-point grid was employed. Gaussian smearing of 50 meV was used during structural optimization, whereas for total energy calculations we employed the more accurate tetrahedron method with Blöchl correction¹¹. During structural relaxation all symmetry constraints were turned off. The energy convergence thresholds for the electronic and ionic relaxation degrees of freedom were 10^{-6} and 10^{-5} eV respectively. The relaxed atomic configurations of different NiMPc MOF monolayers in the POSCAR format of VASP are included separately as Supplementary Data.

Supplementary Figures



Figure S1 | Electronic band structures of different NiMPc 2D MOFs with square-planar NiN₄ moieties. (a-f) show the band structures for CrPc, FePc, CoPc, NiPc, CuPc and ZnPc based NiMPc MOF monolayer systems respectively.



Figure S2 | DFT-relaxed atomistic configuration, electronic band structure and the corresponding PDOS of NiMnPc 2D MOFs with square-planar NiO₄ or NiS₄ moieties. In (**a**-**b**), the linker atoms in the square-planar moieties are oxygen, and in (**c**-**d**), the linker atoms are sulfur. Both systems have ferromagnetic ground states. The exchange energy evaluated in the $\sqrt{2} \times \sqrt{2}$ structural supercell is 279 meV and 168 meV for the system with oxygen and sulfur linkers respectively. The magnetic anisotropy energy was each determined to be 0.57 meV and 0.73 meV in unit cell.



Figure S3 | Ferromagnetic transition temperature T_c as a function of magnetic anisotropy parameter γ for 2D Heisenberg model with single-ion anisotropy. The dashed line denotes the T_c of 2D Ising model ($T_c \approx 2.269 \ J/k_B$).



Figure S4 | Structural models of bulk NiMnPc. (a) Top and side views of bulk stacking configuration in monoclinic lattice. Each unit cell, as outlined in the dashed lines, includes one layer of NiMnPc. (b) Bulk stacking mode corresponding to tetragonal lattice. Each unit cell has two layers with relative in-plane displacement.



Figure S5 | Contributions to bulk system energy change from (a) interlayer hybridization effect and (b) van der Waals interaction, as two NiMnPc MOF monolayers are shifted with respect to each other along the a and b axes. The tetragonal unit cell of the bulk is the same as the one shown in the **Figure 8a** of main text, and interlayer separation is fixed at 3.1 Å. The reference energy in both (a) and (b) is the energy at zero displacement, namely, when the two layers have fully eclipsed AA stacking sequence. To facilitate interpretation of data, the interlayer magnetic coupling was fixed to be antiferromagnetic (AFM) in this case.

Supplementary References

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